

# AUIRLR/U2905

### **Thermal Resistance**

	Parameter	Тур.	Max.	Units
$R_{\theta JC}$	Junction-to-Case ©		1.4	
$R_{\theta JA}$	Junction-to-Ambient (PCB mount) <sup>⑤</sup>		50	°C/W
R <sub>0JA</sub>	Junction-to-Ambient		110	

### Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise specified)

•	Parameter	Min.	Тур.	Max.	Units	Conditions
V <sub>(BR)DSS</sub>	Drain-to-Source Breakdown Voltage	55			V	$V_{GS} = 0V, I_D = 250\mu A$
$\Delta V_{(BR)DSS}/\Delta T_{J}$	Breakdown Voltage Temp. Coefficient		0.070		V/°C	Reference to 25°C, I <sub>D</sub> = 1mA
				0.027		V <sub>GS</sub> = 10V, I <sub>D</sub> = 25A ⊕
R <sub>DS(on)</sub>	Static Drain-to-Source On-Resistance			0.030	Ω	V <sub>GS</sub> = 5.0V, I <sub>D</sub> = 25A ④
				0.040		V <sub>GS</sub> = 4.0V, I <sub>D</sub> = 21A ④
V <sub>GS(th)</sub>	Gate Threshold Voltage	1.0		2.0	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$
gfs	Forward Transconductance	21			S	$V_{DS} = 25V, I_{D} = 25A$
I <sub>DSS</sub>	Drain-to-Source Leakage Current			25	μΑ	$V_{DS} = 55V, V_{GS} = 0V$
				250		$V_{DS} = 44V, V_{GS} = 0V, T_{J} = 150^{\circ}C$
I <sub>GSS</sub>	Gate-to-Source Forward Leakage			100	nA	V <sub>GS</sub> = 16V
	Gate-to-Source Reverse Leakage			-100		V <sub>GS</sub> = -16V

### Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise specified)

	Parameter	Min.	Тур.	Max.	Units	Conditions
$Q_g$	Total Gate Charge			48		$I_D = 25A$
Q <sub>gs</sub>	Gate-to-Source Charge			8.6	nC	$V_{DS} = 44V$
$Q_{gd}$	Gate-to-Drain ("Miller") Charge			25		V <sub>GS</sub> = 5.0V <sup>(4)</sup>
t <sub>d(on)</sub>	Turn-On Delay Time		11			$V_{DD} = 28V$
t <sub>r</sub>	Rise Time		84			$I_D = 25A$
t <sub>d(off)</sub>	Turn-Off Delay Time		26		ns	$R_G = 3.4\Omega$
t <sub>f</sub>	Fall Time		15			$V_{GS} = 5.0V, R_{D} = 1.1\Omega$ ④
$L_D$	Internal Drain Inductance		4.5			Between lead,
					nH	6mm (0.25in.)
L <sub>S</sub>	Internal Source Inductance		7.5			from package
						and center of die contact
C <sub>iss</sub>	Input Capacitance		1700			$V_{GS} = 0V$
Coss	Output Capacitance		400			$V_{DS} = 25V$
C <sub>rss</sub>	Reverse Transfer Capacitance		150		pF	f = 1.0MHz, See Fig. 5

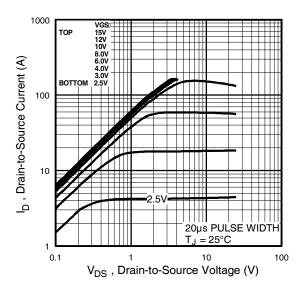
### **Diode Characteristics**

	Parameter	Min.	Тур.	Max.	Units	Conditions	
IS	Continuous Source Current			42		MOSFET symbol	
	(Body Diode)				Α	showing the	
I <sub>SM</sub>	Pulsed Source Current			160		integral reverse	
	(Body Diode) ①					p-n junction diode.	
$V_{SD}$	Diode Forward Voltage			1.3	V	$T_J = 25^{\circ}C$ , $I_S = 25A$ , $V_{GS} = 0V$ $^{\textcircled{4}}$	
dv/dt	Peak Diode Recovery ③		5.0		V/ns	$T_J = 175$ °C, $I_S = 25A$ , $V_{DS} = 55V$	
t <sub>rr</sub>	Reverse Recovery Time		80	120	ns	$T_J = 25^{\circ}C, I_F = 25A$	
Q <sub>rr</sub>	Reverse Recovery Charge		210	320	nC	di/dt = 100A/µs <sup>④</sup>	
t <sub>on</sub>	Forward Turn-On Time	Intrinsic turn-on time is negligible (turn-on is dominated by L <sub>S</sub> +L <sub>D</sub> )					

#### Notes:

- Repetitive rating; pulse width limited by max. junction temperature. ( See fig. 11 )
- ②  $V_{DD}$  = 25V, starting  $T_J$  = 25°C, L =470 $\mu$ H  $R_G$  = 25 $\Omega$ ,  $I_{AS}$  = 25A. (See Figure 12)
- $\label{eq:loss} \begin{array}{l} \text{ } \mathbb{J}_{SD}\!\leq\!25\text{A, di/dt}\!\leq\!270\text{A/}\mu\text{s, V}_{DD}\!\leq\!V_{(BR)DSS},\\ T_{J}\!\leq\!175^{\circ}\text{C} \end{array}$
- 4 Pulse width  $\leq$  300 $\mu$ s; duty cycle  $\leq$  2%.
- S When mounted on 1" square PCB (FR-4 or G-10 Material). For recommended footprint and soldering techniques refer to application note #AN-994.
- $^{\circ}$  R $_{\theta}$  is measured at Tj approximately 90°C.





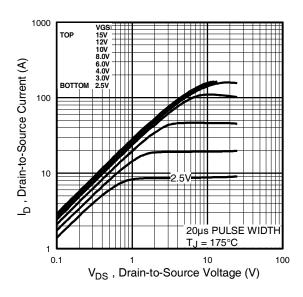
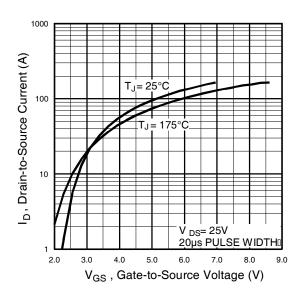


Fig 1. Typical Output Characteristics

Fig 2. Typical Output Characteristics



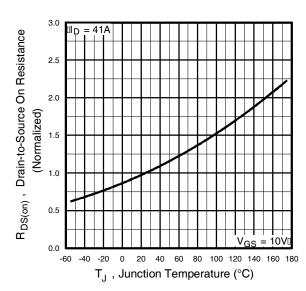
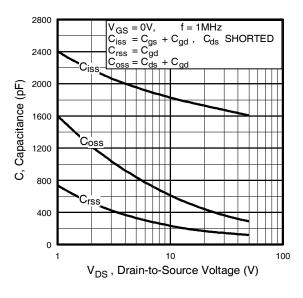
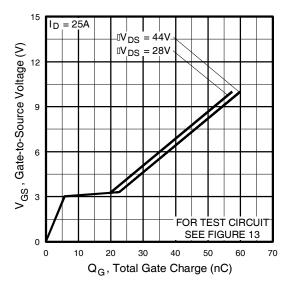


Fig 3. Typical Transfer Characteristics

Fig 4. Normalized On-Resistance Vs. Temperature

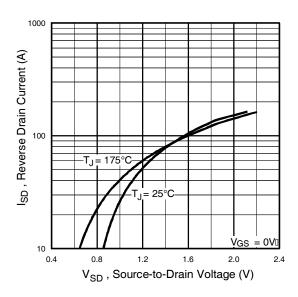






**Fig 5.** Typical Capacitance Vs. Drain-to-Source Voltage

**Fig 6.** Typical Gate Charge Vs. Gate-to-Source Voltage



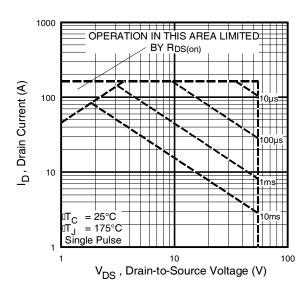
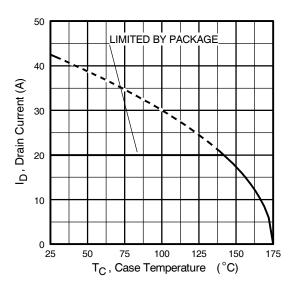


Fig 7. Typical Source-Drain Diode Forward Voltage

Fig 8. Maximum Safe Operating Area





**Fig 9.** Maximum Drain Current Vs. Case Temperature

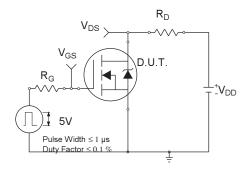


Fig 10a. Switching Time Test Circuit

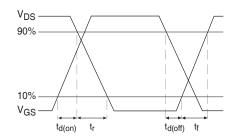


Fig 10b. Switching Time Waveforms

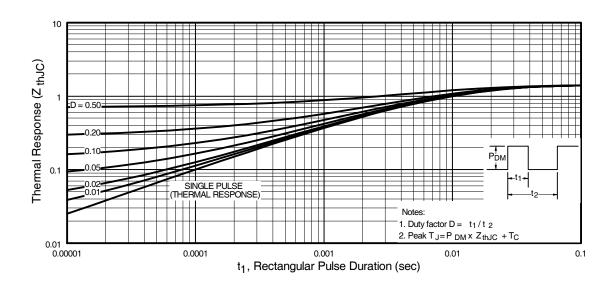


Fig 11. Maximum Effective Transient Thermal Impedance, Junction-to-Case



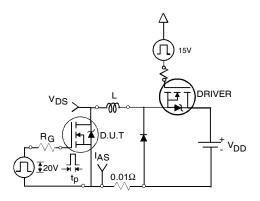


Fig 12a. Unclamped Inductive Test Circuit

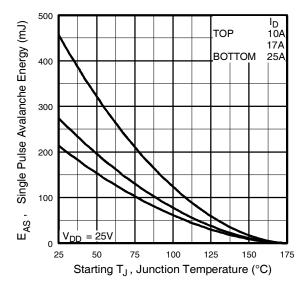
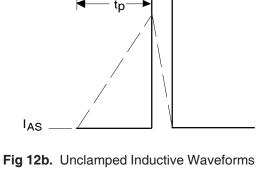


Fig 12c. Maximum Avalanche Energy Vs. Drain Current

V<sub>(BR)DSS</sub>  $I_{AS}$ 



10 V  $\mathsf{Q}_{\mathsf{GD}}$ Q<sub>GS</sub> - $V_{\mathsf{G}}$ Charge -

Fig 13a. Basic Gate Charge Waveform

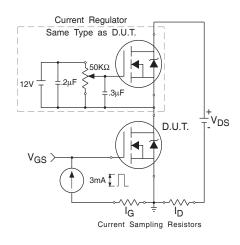
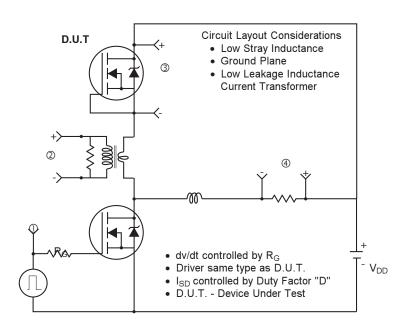
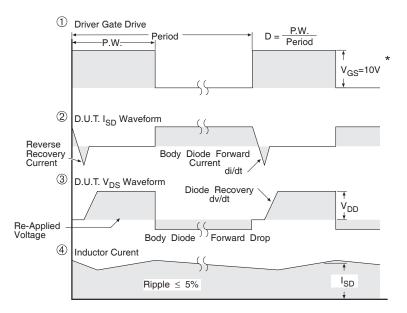


Fig 13b. Gate Charge Test Circuit



### Peak Diode Recovery dv/dt Test Circuit





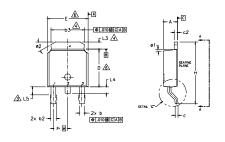
<sup>\*</sup>  $V_{GS}$  = 5V for Logic Level Devices

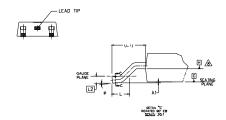
Fig 14. For N-Channel HEXFETS

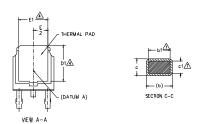


### D-Pak (TO-252AA) Package Outline

Dimensions are shown in millimeters (inches)







- 1.- DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994
- 2.- DIMENSION ARE SHOWN IN INCHES [MILLIMETERS].
- A- LEAD DIMENSION UNCONTROLLED IN L5.
- A- DIMENSION DI, E1, L3 & 63 ESTABLISH A MINIMUM MOUNTING SURFACE FOR THERMAL PAD.

  5.- SECTION C-C DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN .005 AND 0.10 [0.13 AND 0.25] FROM THE LEAD TIP.
- DIMENSION D & E DO NOT INCLUDE MOLD FLASH, MOLD FLASH SHALL NOT EXCEED .005 [0.13] PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY.
- DIMENSION b1 & c1 APPLIED TO BASE METAL ONLY.

  B- DATUM A & B TO BE DETERMINED AT DATUM PLANE H.
- 9.- DUTLINE CONFORMS TO JEDEC OUTLINE TO-252AA.

S Y M	DIMENSIONS					
B	MILLIM	ETERS	INC	Ö		
O L	MIN.	MAX.	MIN,	MAX.	Ė	
А	2.18	2.39	.086	.094		
A1	-	0.13	-	.005		
ь	0.64	0.89	.025	.035		
ь1	0.65	0.79	.025	.031	7	
b2	0.76	1.14	.030	.045		
b3	4.95	5,46	.195	.215	4	
c	0,46	0.61	.018	.024		
c1	0,41	0.56	.016	.022	7	
c2	0.46	0.89	.018	.035		
D	5.97	6.22	.235	.245	6	
D1	5,21	-	.205	-	4	
E	6.35	6.73	.250	.265	6	
E1	4.32	-	.170	-	4	
e	2.29	BSC	.090	BSC		
н	9.40	10.41	.370	.410		
L	1.40	1.78	.055	.070		
L1	2.74	BSC	.108	REF.		
L2	0.51	BSC	.020 BSC			
L3	0,89	1.27	.035	.050	4	
L4	-	1.02	-	.040		
L5	1,14	1.52	.045	.060	3	
ø	0.	10*	0.	10*		
ø1	0.	15"	0,	15*		
ø2	25*	35*	25*	35*		

#### LEAD ASSIGNMENTS

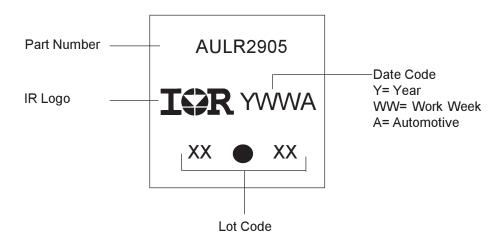
#### HEXFET

- 1.- GATE 2.- DRAIN 3.- SOURCE 4.- DRAIN

#### IGBT & CoPAK

- 1.- GATE 2.- COLLECTOR 3.- EMITTER 4.- COLLECTOR

## D-Pak Part Marking Information

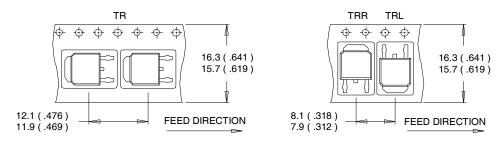


Note: For the most current drawing please refer to IR website at http://www.irf.com/package/



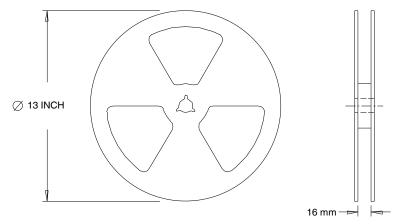
### D-Pak (TO-252AA) Tape & Reel Information

Dimensions are shown in millimeters (inches)



#### NOTES:

- 1. CONTROLLING DIMENSION: MILLIMETER.
- 2. ALL DIMENSIONS ARE SHOWN IN MILLIMETERS ( INCHES ).
- 3. OUTLINE CONFORMS TO EIA-481 & EIA-541.



#### NOTES:

1. OUTLINE CONFORMS TO EIA-481.

Note: For the most current drawing please refer to IR website at http://www.irf.com/package/



Qualification Level		Automotive						
		(per AEC-Q101)						
			. ,	passed Automotive level is granted by ea	e qualification. IR's ktension of the higher			
Mailatana Canadiliaita Land		D-PAK		MSL1				
worsture S	Sensitivity Level	I-PAK		MSL1				
	Machine Model	Class M4 (+/- 425V) <sup>††</sup>						
		AEC-Q101-002						
	Human Body Model	Class H1B (+/- 1000V) <sup>††</sup>						
ESD		AEC-Q101-001						
	Charged Device Model	Class C5 (+/- 1125V) <sup>††</sup>						
		AEC-Q101-005						
RoHS Compliant		Yes						

<sup>†</sup> Qualification standards can be found at International Rectifier's web site: http://www.irf.com/

<sup>††</sup> Highest passing voltage.



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